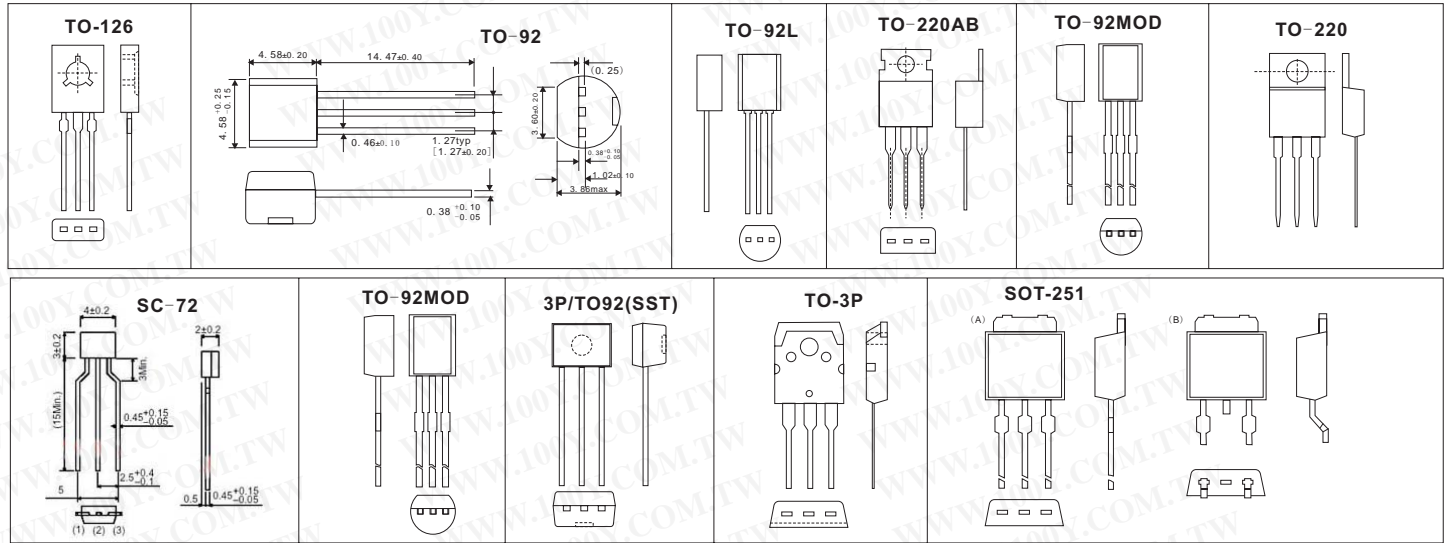


# Semiconductors-Discretes

## 2SC~Series Transistors

Detailed product specifications are available on: [us.100y.com.tw](http://us.100y.com.tw)



Part No.	Product No.	Manufacturer	Description	Application	Pol	Ic(max)	Pc(max)	Vceo(max)	hfe(min.-max.)	Pins/Package
13612	2SC1162C	HITACHI	Bipolar power general purpose transistor	LF PA	NPN	2.5A	0.75W	35V	60-320	3P/TO-126
5860	2SC1213ACTZ-E	HITACHI	Silicon NPN Epitaxial	LF A	NPN	0.5A	0.4W	35V	60-320	3P/TO-92
22149	2SC1359C	MATSUSHITA	Silicon NPN epitaxial planer type small signal transistor		NPN					3P/TO-92
4892	2SC1384	Panasonic	NPN epitaxial planear transistor	For low-frequency power amplification and driver amplification	NPN	1A	1W	50V	85-340	3P/TO-92L
40232	2SC1384	TOSHIBA	NPN epitaxial planear transistor		NPN	1A		50V		3P/TO-92L
22150	2SC1384R	MATSUSHITA	Silicon NPN epitaxial planer type small signal transistor		NPN					3P/TO-92L
16178	2SC1569		Transistor	CRT Cout	NPN	0.15A	1.5W	300V	40-170	3P/TO-220AB
4897	2SC1674	NEC	Silicon NPN Transistor High frequency applications	FM RF/MIX	NPN	0.02A	0.25W	20V	40-180	3P/TO-92
4898	2SC1675		Silicon NPN Transistor High frequency applications	FM/AM RF/MIX	NPN	0.03A	0.25W	30V	40-180	3P/TO-92
3765	2SC1730		Transistor For VHF, UHF	VHF,UHF	NPN	0.05	0.25W	15V	40-180	3P/TO-92
3761	2SC1740S	ROHM	General purpose transistor		NPN	0.1A	0.3W	40V	120-820	3P/TO-92
18613	2SC1775AE	HITACHI	Silicon PNP Epitaxial		PNP	-50mA	300mW	-120V	250-800	3P/TO-92
40198	2SC1815	TOSHIBA	Transistor silicon NPN epitaxial type		NPN	0.15A	0.4W	50V	70-140	TO-92
3357	2SC1815-GR	TOSHIBA	NPN epitaxial silicon transistor	Audio Frequency General Purpose Amplifier Applications Driver Stage Amplifier Applications	NPN	0.15A	0.4W	50V	200-400	3P/TO-92
39868	2SC1815-Y	TOSHIBA	NPN epitaxial silicon transistor		NPN	0.15A	0.4W	50V	200-400	3P/TO-92
39395	2SC1815GR-E	TOSHIBA	NPN epitaxial silicon transistor	Audio Frequency General Purpose Amplifier Applications Driver Stage Amplifier Applications	NPN	0.15A	0.4W	50V	200-400	3P/TO-92
5727	2SC1906TZ	HITACHI	Silicon NPN Epitaxial Planar	VHF A/MIX/OSC	NPN	0.05A	0.3W	19V	40(min)	3P/TO-92
5861	2SC1907	HITACHI	Small signal general purpose transistor	UHF A/OSC	NPN	0.05A	0.3W	19V	40(min)	3P/TO-92
41101	2SC1921CTZ	HITACHI	NPN Triple Diffused		NPN	50mA	600mW	200V	30-300	TO-92MOD
41014	2SC1959	TOSHIBA	Silicon PNP Epitaxial Transistor	LF PA	PNP	500mA	500mW	35V	70-400	TO-92
5862	2SC2001	NEC	Transistor. General purpose applications high total power disipation	LF A	NPN	0.7A	0.6W	25V	90-400	3P/TO-92
14861	2SC2001L-T	NEC	NPN silicon transistor		NPN	700mA	0.6W	25V	90-400	3P/TO-92
5863	2SC2073	Fairchild	NPN silicon power transistor	PA/Vout	NPN	1.5A	1.5W	150V	40-140	3P/TO-220AB
5864	2SC2120-Y	TOSHIBA	Silicon NPN transistor for audio power amplifier applications	LF PA	NPN	0.8A	0.6W	30V	160-3200	3P/TO-92
5865	2SC2229	Fairchild	Silicon NPN transistor	HV SW/Vout	NPN	0.05A	0.8W	150V	70-240	3P/TO-92L
13611	2SC2236-Y	TOSHIBA	Silicon NPN transistor for audio power amplifier and driver stage amplifier applications	LF PA	NPN	1.5A	0.9W	30V	100-320	3P/TO-92L
5866	2SC2240		General-Purpose Small-Signal Transistors	LF LN A	NPN	0.1A	0.3W	120V	200-700	3P/TO-92
22153	2SC2320-E		NPN Transistor		NPN	0.2A	0.3W	50V		
5870	2SC2331		Transistor	HS PSW	NPN	2A	1.5W	100V	40-200	3P/TO-220AB

